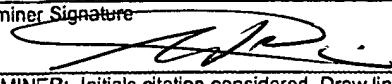


Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 14925-010001	Application No. Unknown
<b>Information Disclosure Statement by Applicant</b> (Use several sheets if necessary)  (37 CFR §1.98(b))		Applicant Takao Nakamura et al.	
		Filing Date March 23, 2004	Group Art Unit Unknown

<b>U.S. Patent Documents</b>							
Examiner Initial	Desig. ID	Document Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
WSL	AA	5,396,103	03/07/1995	Oiu et al.			
WSL	AB	5,548,137	08/20/1996	Fan et al.			
	AC						
	AD						
	AE						

<b>Foreign Patent Documents or Published Foreign Patent Applications</b>							
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation
							Yes      No
WSL	AF	06-310815	11/04/1994	Japan			X (Abstract Only)
WSL	AG	06-005920	01/14/1994	Japan			X (Abstract Only)
	AH						

<b>Other Documents (include Author, Title, Date, and Place of Publication)</b>		
Examiner Initial	Desig. ID	Document
WSL	AI	Takao Nakamura et al., Optronics (2000) No. 12, pp.126-131 (partial translation)
WSL	AJ	Y. Fan et al., "Graded band gap ohmic contact to p-ZnSe", <u>Appl. Phys. Lett.</u> , 61 (26), 12/28/1992, pp. 3160-3162
	AK	

Examiner Signature 	Date Considered 6/3/05
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	